

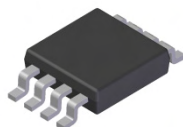
Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Low Gate Resistance
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

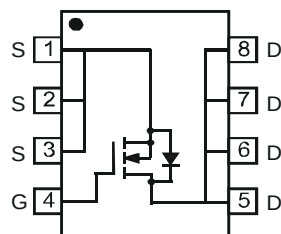
Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Page 5
- Ordering Information: See Page 5
- Weight: 0.072 grams (approximate)

SO-8



TOP VIEW


 TOP VIEW
 Internal Schematic

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 3)	Steady State	T _A = 25°C	I _D	10	A
		T _A = 85°C		6	
Pulsed Drain Current (Note 4)			I _{DM}	60	A
Avalanche Current (Notes 4 & 5)			I _{AR}	16	A
Repetitive Avalanche Energy (Notes 4 & 5) L = 0.1mH			E _{AR}	12.8	mJ

Thermal Characteristics

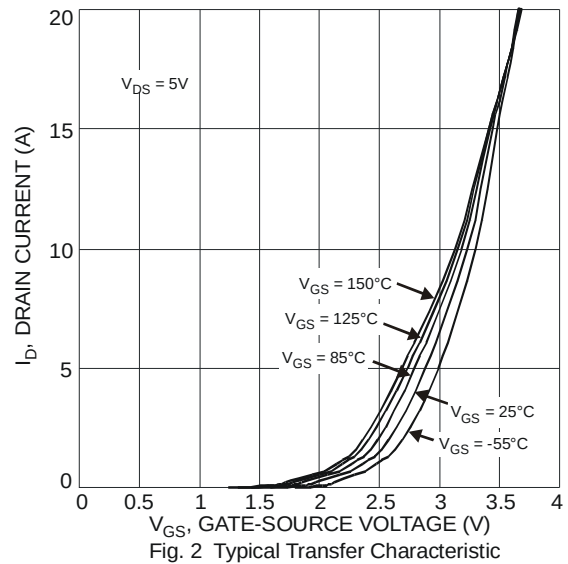
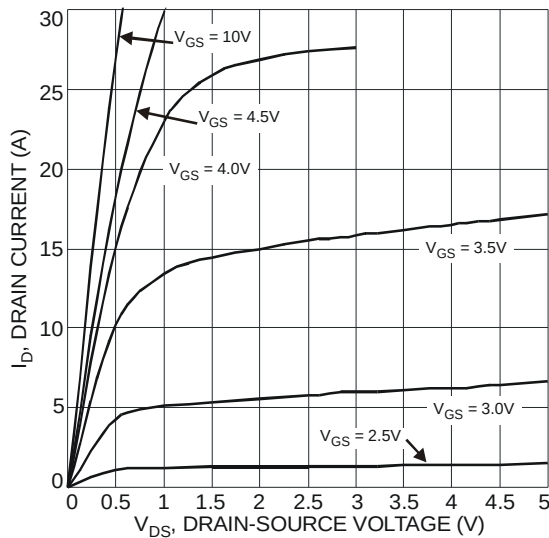
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	P _D	1.42	W
Thermal Resistance, Junction to Ambient @T _A = 25°C (Note 3)	R _{θJA}	88.4	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at <http://www.diodes.com>.
 3. Device mounted on FR-4 substrate PC board with minimum recommended pad layout in a still air environment @ T_A = 25°C. The value in any given application depends on the user's specific board design.
 4. Repetitive rating, pulse width limited by junction temperature.
 5. I_{AR} and E_{AR} rating are based on low frequency and duty cycles to keep T_J = 25°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	V _{GS} = 0V, I _D = 250μA
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1	μA	V _{DS} = 30V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	V _{GS} = ±20V, V _{DS} = 0V
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(th)}	1.0	1.45	2.4	V	V _{DS} = V _{GS} , I _D = 250μA
Static Drain-Source On-Resistance	R _{DS(on)}	-	15 25	23 33	mΩ	V _{GS} = 10V, I _D = 10A V _{GS} = 4.5V, I _D = 7.5A
Forward Transfer Admittance	Y _{fs}	-	2.5	-	S	V _{DS} = 5V, I _D = 10A
Diode Forward Voltage	V _{SD}	-	0.69	1	V	V _{GS} = 0V, I _S = 1A
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	C _{iss}	-	478.9	-	pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	-	96.7	-	pF	
Reverse Transfer Capacitance	C _{rss}	-	61.4	-	pF	
Gate Resistance	R _g	0.4	1.1	1.6	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz
Total Gate Charge (V _{GS} = 4.5V)	Q _g	-	5.0	8	nC	V _{DS} = 15V, V _{GS} = 10V, I _D = 10A
Total Gate Charge (V _{GS} = 10V)	Q _g	-	10.5	17	nC	
Gate-Source Charge	Q _{gs}	-	1.8	-	nC	
Gate-Drain Charge	Q _{gd}	-	1.6	-	nC	
Turn-On Delay Time	t _{D(on)}	-	2.9	-	ns	V _{GS} = 10V, V _{DS} = 15V, R _G = 3Ω, R _L = 1.5Ω
Turn-On Rise Time	t _r	-	7.9	-	ns	
Turn-Off Delay Time	t _{D(off)}	-	14.6	-	ns	
Turn-Off Fall Time	t _f	-	3.1	-	ns	

Notes: 6. Short duration pulse test used to minimize self-heating effect.
7. Guaranteed by design. Not subject to production testing.



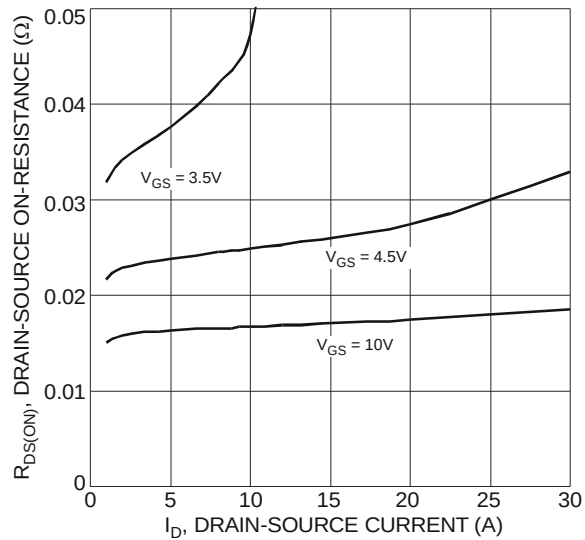


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

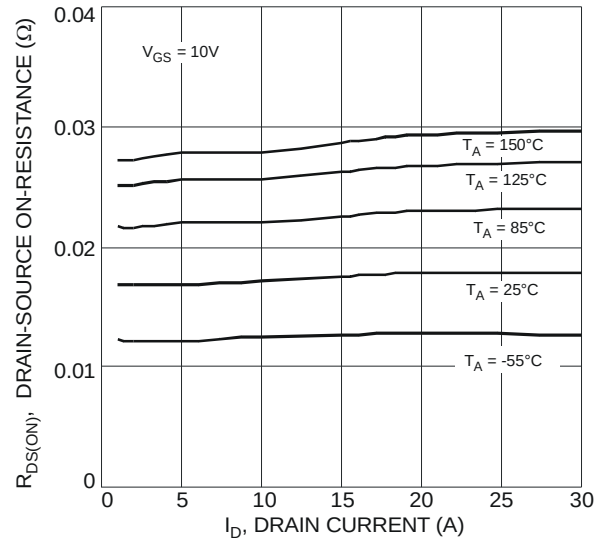


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

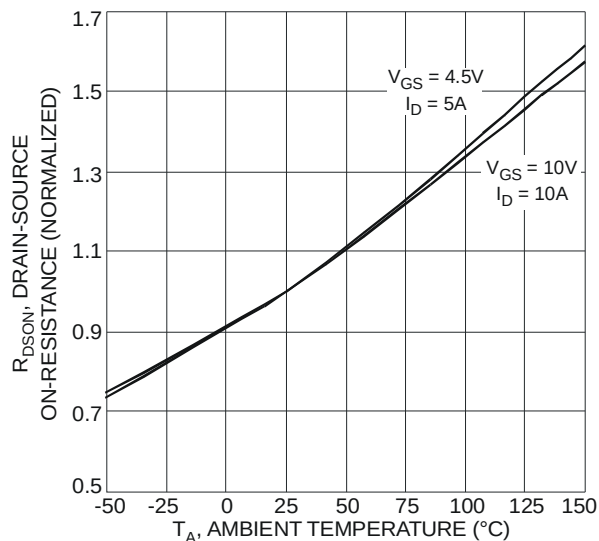


Fig. 5 On-Resistance Variation with Temperature

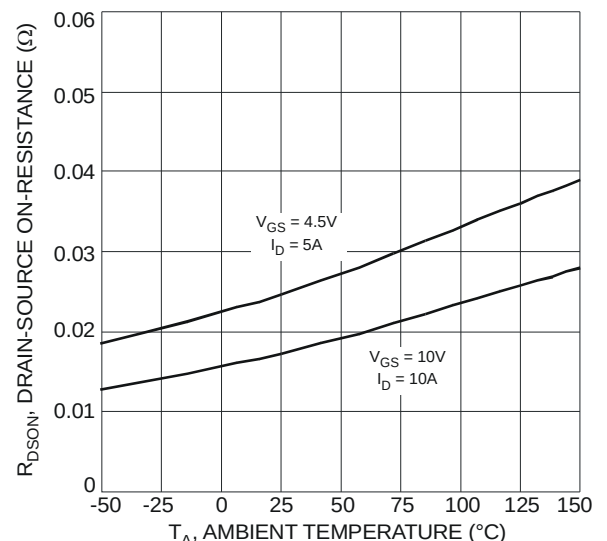


Fig. 6 On-Resistance Variation with Temperature

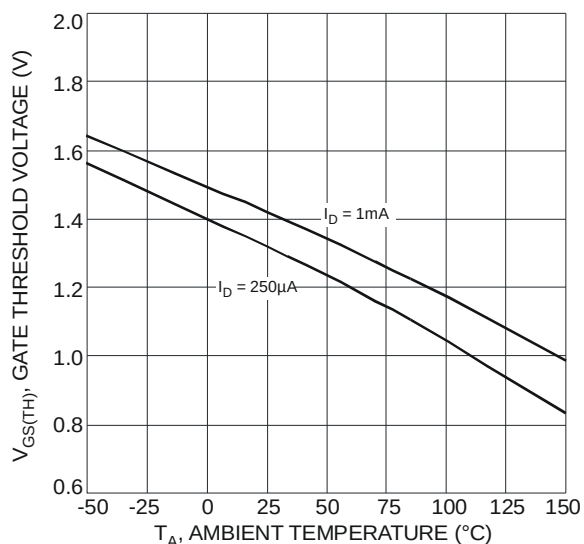


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

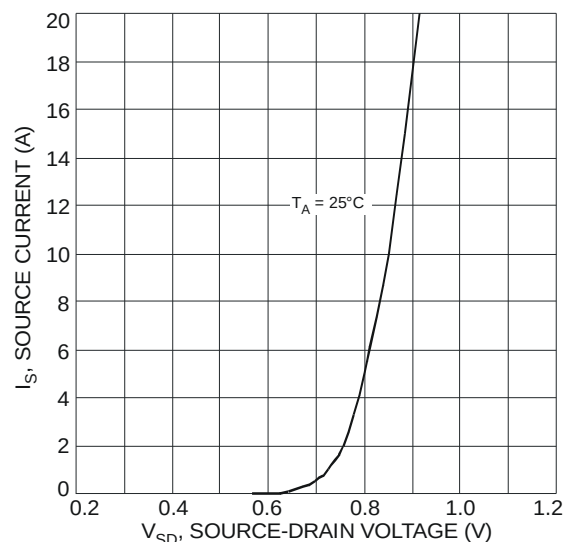


Fig. 8 Diode Forward Voltage vs. Current

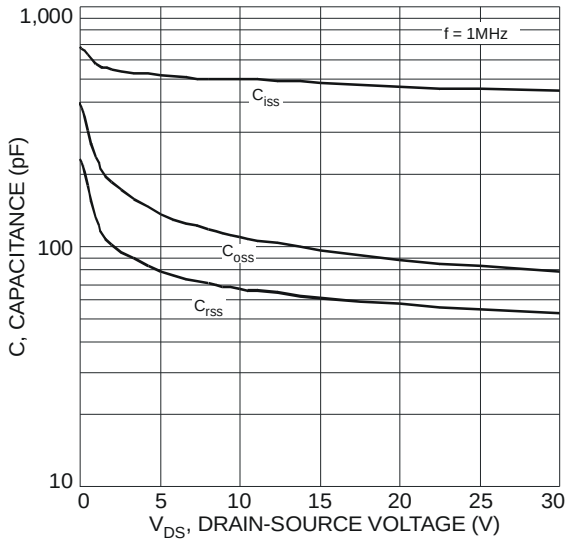


Fig. 9 Typical Total Capacitance

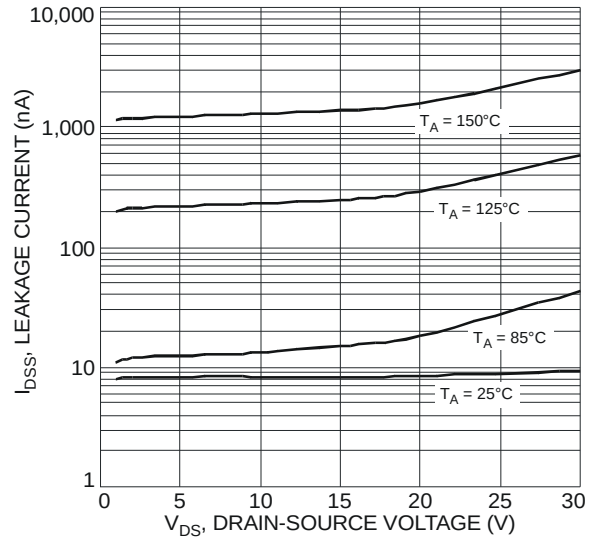


Fig. 10 Typical Leakage Current vs. Drain-Source Voltage

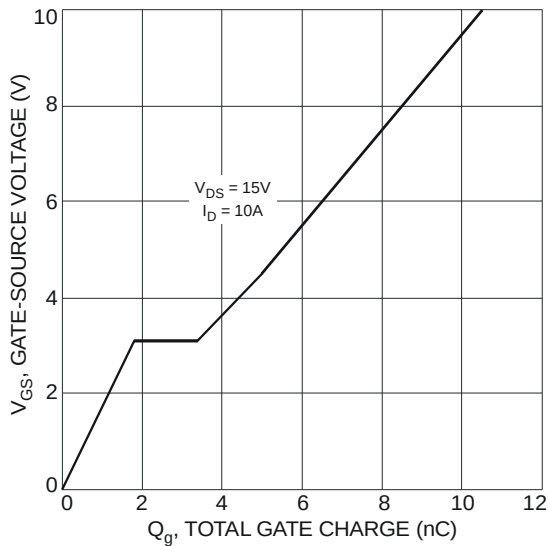


Fig. 11 Gate-Charge Characteristics

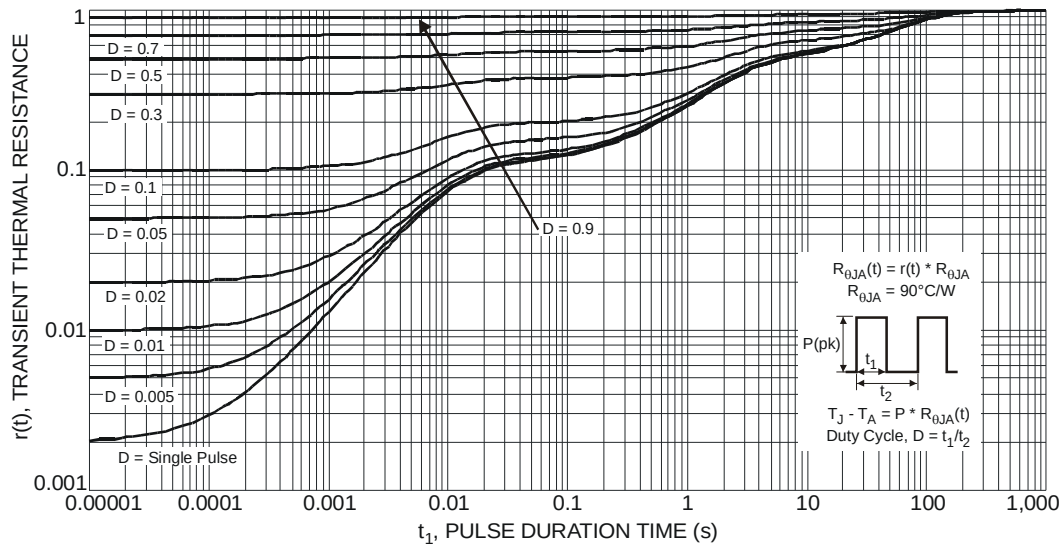


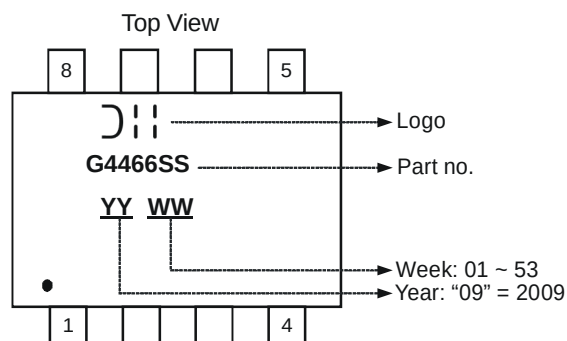
Fig. 12 Transient Thermal Response

Ordering Information (Note 8)

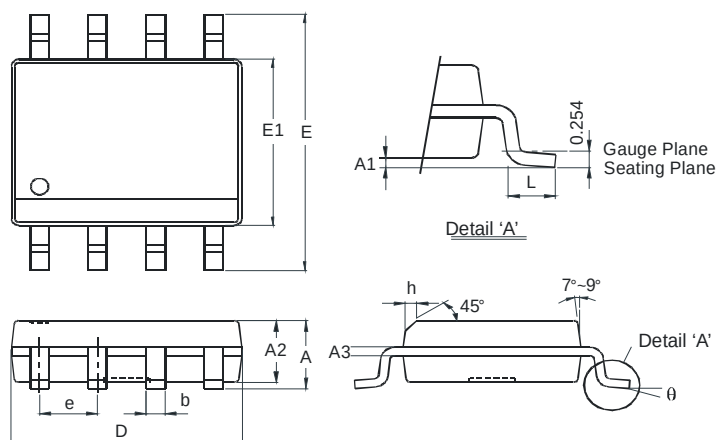
Part Number	Case	Packaging
DMG4466SSSL-13	SO-8	2500 / Tape & Reel

Notes: 8. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information

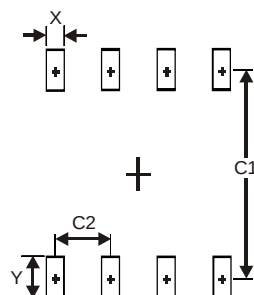


Package Outline Dimensions



SO-8		
Dim	Min	Max
A	-	1.75
A1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
E	5.90	6.10
E1	3.85	3.95
e	1.27 Typ	
h	-	0.35
L	0.62	0.82
θ	0°	8°
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27

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